FAIRCHILD

SEMICONDUCTOR®

FCH47N60F F085

N-Channel MOSFET

600V, **47A**, **75m**Ω

Features

- Typ $r_{DS(on)}$ = 66m Ω at V_{GS} = 10V, I_D = 47A
- Typ Q_{q(tot)} = 190nC at V_{GS} = 10V, I_D = 47A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Description

SuperFETTM is Fairchild's proprietary new generation of high voltage MOSFETs utilizing an advanced charge balance mechanism for outstanding low on-resistance and lower gate charge performance.

This advanced technology has been tailored to minimize conduction loss, provide superior switching performance, and withstand extreme dv/dt rate and higher avalanche energy. Consequently, SuperFET is suitable for various automotive DC/DC power conversion.

Applications

- Automotive On Board Charger
- Automotive DC/DC converter for HEV

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{DSS}	Drain to Source Voltage		600	V
V _{GS}	Gate to Source Voltage		±30	V
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	47	٨
		T _C = 25°C	See Figure4	— A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	810	mJ
Р	Power Dissipation		417	W
P _D	Derate above 25°C		3.3	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 150	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case		0.3	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	50	°C/W

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Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FCH47N60F	FCH47N60F_F085	TO-247	-	-	30 units

Notes:

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^{\circ}$ C, L = 5mH, $I_{AS} = 18A$, $V_{DD} = 100$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche

3: R_{0.IA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

TO-247 For current package drawing, please refer to the Fairchild website at www.fairchildsemi.com/packaging

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Electrical Characteristics T _J = 25°C unless otherwise noted							
Symbol	Parameter	Test Conditions		Min	Тур	Max	Units
Off Cha	racteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V	′ _{GS} = 0V	600	-	-	V
	Drain to Source Lookage Current	V _{DS} =600V,	T _J = 25 ^o C	-	-	10	μA
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V$	$T_J = 150^{\circ}C(Note 4)$	-	-	1	mA
I _{GSS}	Gate to Source Leakage Current	V_{GS} = ±30V		-	-	±100	nA
	Cate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D	₀ = 250μA	3.0	4.0	5.0	V
r	Drain to Source On Resistance	I _D = 47A,		-	66	75	mΩ
r _{DS(on)}		V _{GS} = 10V	$T_J = 150^{\circ}C(Note 4)$	-	180	223	mΩ
Dynami	c Characteristics						
C _{iss}	Input Capacitance			-	5900	8000	pF
C _{oss}	Output Capacitance			-	3200	4200	pF
C _{rss}	Reverse Transfer Capacitance			-	250	-	pF

C _{iss}	Input Capacitance		– V _{DS} = 25V, V _{GS} = 0V, – f = 1MHz		5900	8000	pF
C _{oss}	Output Capacitance				3200	4200	pF
C _{rss}	Reverse Transfer Capacitance				250	-	pF
R _g	Gate Resistance	f = 1MHz	f = 1MHz		1	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V	V _{DD} = 300V	-	190	250	nC
Q _{g(th)}	Threshold Gate Charge	V _{GS} = 0 to 2V			12	18	nC
Q _{gs}	Gate to Source Gate Charge		—	-	40	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	96	-	nC

Switching Characteristics

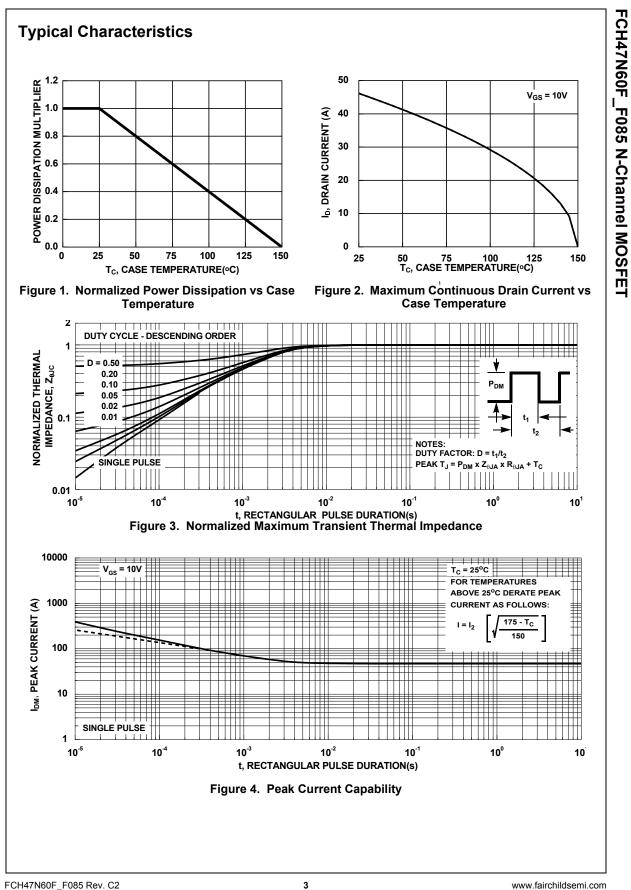
t _{on}	Turn-On Time		-	-	410	ns
t _{d(on)}	Turn-On Delay Time		-	110	-	ns
t _r	Rise Time	V _{DD} = 300V, I _D = 47A,	-	160	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{DD} = 300V, I _D = 47A, V _{GS} = 10V, R _G = 25Ω	-	540	-	ns
t _f	Fall Time		-	125	-	ns
t _{off}	Turn-Off Time		-	-	1000	ns

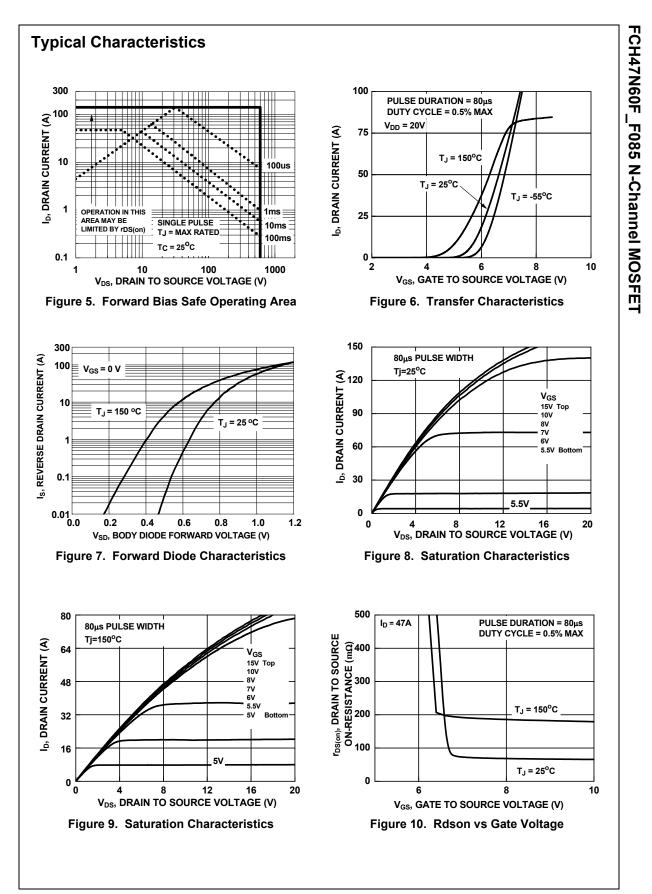
Drain-Source Diode Characteristics

V.	Source to Drain Diode Voltage	I _{SD} = 47A, V _{GS} = 0V	-	-	1.4	V
V _{SD}		I _{SD} = 23.5A, V _{GS} = 0V	-	-	1.25	V
T _{rr}	Reverse Recovery Time	I _F = 47A, dI _{SD} /dt = 100A/μs,	-	207	350	ns
Q _{rr}	Reverse Recovery Charge	V _{DD} =480V	-	2.0	3.6	uC

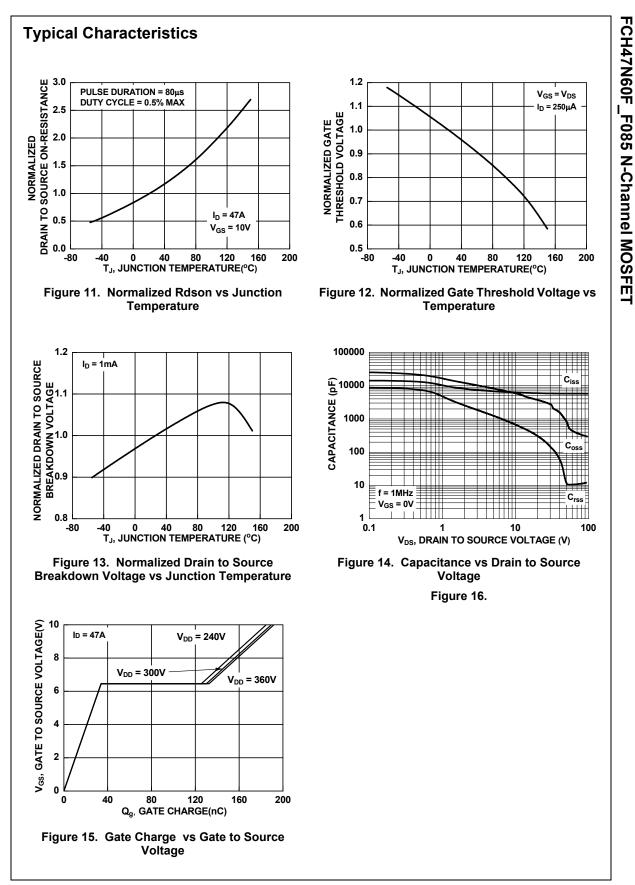
Notes:

4: The maximum value is specified by design at T_J = 150°C. Product is not tested to this condition in production.





FCH47N60F_F085 Rev. C2



FCH47N60F_F085 Rev. C2



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